

BSC017N04NS G

Request a Quote

BSC017N04NS G Information

		BSC017N04NS G Infineon Technologies	F
wyournelsener.com	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 40V 100A TDSON-8	
F. 1	Package	8-PowerTDFN	
		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSC017N04NS G Specifications

Manufacturer Part Number	BSC017N04NS G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	30A (Ta), 100A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 85µA
Gate Charge (Qg) (Max) @ Vgs	108nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	8800pF @ 20V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2.5W (Ta), 139W (Tc)
Rds On (Max) @ Id, Vgs	1.7 mOhm @ 50A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TDSON-8
Package / Case	8-PowerTDFN
	Report errors?

BSC017N04NS G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BSC017N04NS G Payment Methods



BSC017N04NS G Shipping Methods



If you have any question about BSC017N04NS G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com